

# SANYO Semiconductors DATA SHEET

# MCH6622 — General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.
- · Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	٧
Gate-to-Source Voltage	VGSS		±20	٧
Drain Current (DC)	ID		1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	4	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm) 1unit	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			I I a is
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	60			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =0.5A	0.45	0.9		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =0.5A, V <sub>G</sub> S=10V		480	630	mΩ
	RDS(on)2	ID=0.3A, VGS=4V		640	900	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		70		pF
Output Capacitance	Coss	VDS=20V, f=1MHz		9		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		6.5		pF

Marking: FW Continued on next page.

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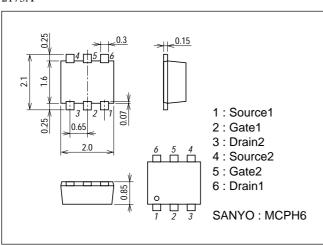
# MCH6622

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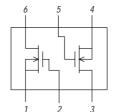
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	td(on)	See specified Test Circuit.		5		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		4		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		12		ns
Fall Time	tf	See specified Test Circuit.		12		ns
Total Gate Charge	Qg	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A		3.0		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A		0.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A		0.6		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0		0.9	1.2	V

# **Package Dimensions**

unit : mm 2173A



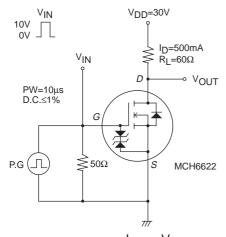
### **Electrical Connection**

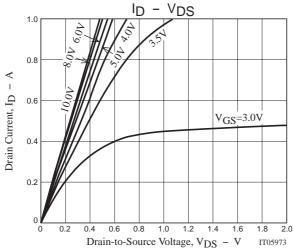


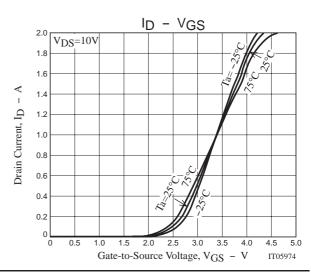
1 : Source1 2 : Gate1 3 : Drain2 4 : Source2 5 : Gate2 6 : Drain1

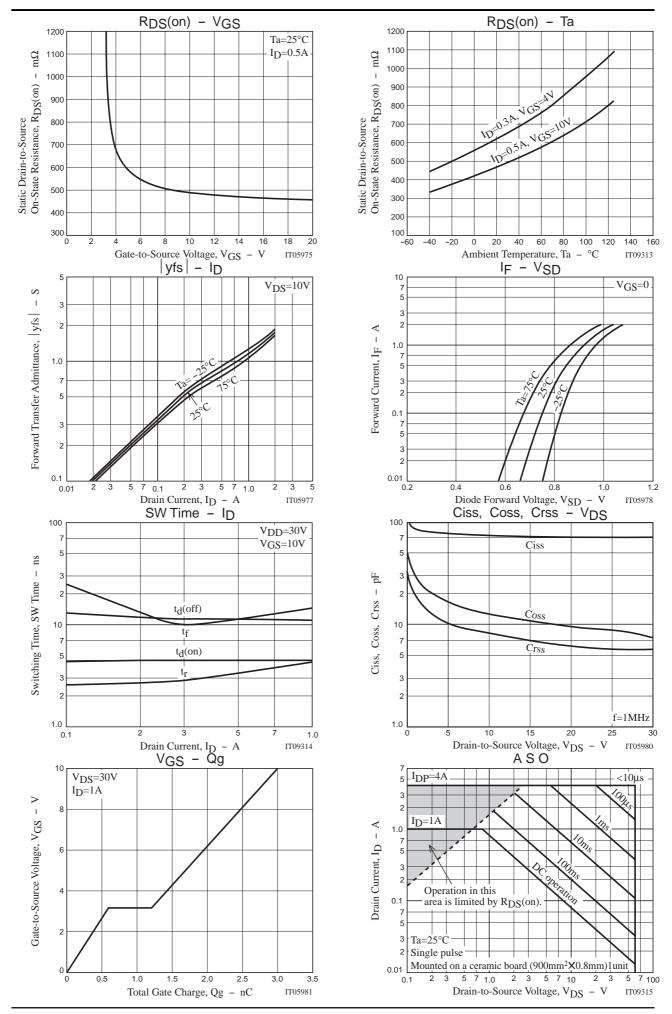
Top view

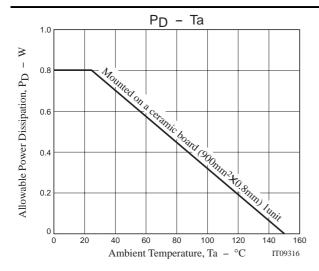
# **Switching Time Test Circuit**











Note on usage: Since the MCH6622 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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